	COUNT	DESCRIPTION	OF REVISI	IONS	BY	CHKD	DATE		COI	UNI	DESCRIPTION OF RE	VISIONS	BA	CHKD	DA	\IE
APF	LICA	BLE STAND	ARD													
		OPERATING	NOF	1 -66 (* 1() ±86 (*(noto1) 1 -							TORAGE -1		-10℃ TO +60℃			
DATINO		TEMPERATURE RA	ANGE	I I I						_	MPERATURE RANGE PLICABLE					., ,
HA	TING	VOLTAGE		1 30 A V.A.A.A.							NNECTOR	BM23FR0.6-**DP-			0.35\	/(**)
		CURRENT		0.3A												
			•			SF	PECIF	FICA	TIC	N	S					
		ITEM			TE	ST ME					REQUIR	EMENT:	S		QT	ΑT
COI	NSTR	UCTION														
GENERAL EXAMINATION			CONFIRM		SUALL	Y AND E	Y MEAS	URING		ACCORDING TO DRAWING.				х	х	
MARKING				CONFIRMED VISUALLY.							†				Х	Х
		CAL CHARA									<u> </u>				^	
©ONTACT RESISTANCE				20mV AC OR LESS 1kHz, 1mA							100mΩ MAX				Х	_
NSULATION RESISTANCE			100V DC							50MΩ MIN					_	
OLTAGE PROOF			100V AC	100V AC FOR 1min.							NO FLASHOVER OR BREAKDOWN				Х	_
ME(CHAN	IICAL CHARA	ACTERIS	TICS	3						!				-	
MPCHANICAI				10 TIMES INSERTIONS AND EXTRACTIONS.							① CONTACT RESISTANCE: 100mΩ MAX					
PERATION S.C. S.C. E. S.C. S.C. S.C. S.C. S.C. S.C. S.C. S.C											② NO DAMAGE, CRACK OR LOOSENESS					_
ร.' ช ∷ .										OF PATRS.				Х		
ZINERA GO CE	ATION		EREQUEN	NCY 1	0 TO 5	5 TO 10	Hz APP	BOX 5m	in		① NO ELECTRICAL DIS	CONTINU	ITY OF	1us		
tulla			SINGLE A	FREQUENCY 10 TO 55 TO 10 Hz, APPROX 5min SINGLE AMPLITUDE 0.75mm, 10CYCLES,							② NO DAMAGE, CRACK OR LOOSENESS				х	_
for			FOR 3 DIRECTIONS.							OF PARTS.						
ZHBCK			490 m/s² DURATION OF PULSE 11ms AT 3 TIMES							① NO ELECTRICAL DISCONTINUITY OF 1µs.						
Sentation for full sentation for			FOR 3 DIRECTIONS.							② NO DAMAGE, CRACK OR LOOSENESS OF PARTS.					_	
ক <u>কু</u> ত ও	/IDON	IMENTAL CH		DIC	TICS						OF PARIS.					
(RAF)	D CHAI	IGE OF	TEMPERA			→ +85°C					① CONTACT RESISTAN	ICF: 1	00mΩ	MAX		l
#EMPERATURE			TIME								② INSULATION RESISTANCE: 50MΩ MIN					i
EMPERATURE E G E G E G E G E G E G E G E			UNDER 5 CYCLES. (RELOCATION TIME TO CHAMBER: WITHIN2~3 MIN)						③ NO DAMAGE, CRACK OR LOOSENESS OF PARTS.				×	_		
BAMP HEAT			EXPOSED AT 40±2°C, 90 TO 95%, 96h.						① CONTACT RESISTANCE: 100mΩ MAX							
STEADY STATE) STEADY STATE) SULPHUR DIOXIDE SULPHUR DIOXIDE										② INSULATION RESISTANCE: 25MΩ MIN				х	l _	
XIIC nta											3 NO DAMAGE, CRACI	K OR LOC	SENES	SS		
G D F	PHUR D	IOXIDE	EXPOSED) IN 2!	5 PPM	FOR 96h	25℃	75±5%F	RН		OF PARTS. ① CONTACT RESISTAN	ICE: 1	00mΩ	MAX		
as a				EXPOSED IN 25 PPM FOR 96h, 25°C, 75±5%RH. (Test standard : JIS C 60068)							C COMMON MACE. TOOMING WITH				х	_
at. ple																
e th									•							

DRAWING FOR REFERENCE

This is subject to change without notice

REMARKS		DRAWN	DESIGNI	ED CHECKED	APPROVED	RELEASED				
Note 1; INCLUDE THE TEMPERATURE RISING	BY CURRENT.	S.H.JUNG	S.H.JUN	NG H.W.JO	T.S.KANG	ENG 16.01.12				
Unless otherwise specified, refer to JIS C 5402	2 and IEC 60512	16.01.12	16.01.1	16.01.12	16.01.12	DEPT				
Note QT: QUALIFICATION TEST AT: ASSURANCE TEST X: APPLICABLE TEST										
HIROSE KOREA CO.,LTD.	SPECIFIC	CATION SHEET PART NO. BM23FR0.6-**DS-0.35V(51)								
		1				1.				